The electromomentum effect in piezoelectric Willis scatterers

René Pernas-Salomón¹, Michael R. Haberman²,³, Andrew N. Norris⁴, and Gal Shmuel*¹

¹Faculty of Mechanical Engineering, Israel Institute of Technology, Haifa, Israel
²Walker Department of Mechanical Engineering, The University of Texas at Austin, Austin, Texas 78712-1591, USA
³Applied Research Laboratories, The University of Texas at Austin, Austin, Texas 78758, USA
⁴Mechanical and Aerospace Engineering, Rutgers University, Piscataway, 2 NJ 08854-8058, USA

Abstract

Materials with asymmetric microstructure can constitutively couple macroscopic fields from different physics. Examples include piezoelectric materials that couple mechanical and electric fields and Willis materials that anomalously couple dynamic and elastic fields. Recently, it was shown that anomalous coupling between the elastodynamic and electric field emerges when piezoelectricity is incorporated into Willis materials. Here, we investigate one-dimensional piezoelectric Willis elements using heuristic homogenization, long-wavelength asymptotic analysis and numerical experiments. We show that an anomalous electromomentum coupling is necessary to explain the scattering properties of the asymmetric piezoelectric media by a macroscopic description that respects reciprocity and energy conservation. Our findings elucidate the origins of the electromomentum coupling and provide insight for the future design of this new class of coupled-field metamaterials.

1 Introduction

Metamaterials are engineered composites materials with extraordinary effective properties that offer functionalities beyond those of standard materials [10, 17, 49, 52, 55]. Prominent examples in elastodynamics and acoustics include metamaterials with negative mass density and negative stiffness, which are in sharp contrast with the positive moduli of their constituents [6, 12, 13, 20]. A separate class of metamaterials, known as Willis materials, exhibit unique properties on the macroscale that their constituents do not possess, namely moduli that couple the momentum and strain fields as well as the velocity to stress fields [21, 22, 24, 31, 44]. Willis materials therefore offer additional degrees of freedom to manipulate mechanical waves similar to the way bianisotropic materials allow greater control over electromagnetic waves [1, 4, 25, 26, 30, 48].

*Corresponding author: meshmuel@technion.ac.il
The emergence of these non-intuitive effective moduli is the result of a homogenization scheme for elastic composites that was initially developed by Willis [56, 57, 60, 61, 62] to understand the elastodynamic response of heterogeneous elastic media, and revisited by many others in the context of metamaterial research [11, 25, 29, 30, 33–36, 39, 43, 46, 54]. Of relevance to this work are the conclusions of Sieck et al. [48] and Muhlestein et al. [31], who demonstrated that the constitutive relations of Willis form are required to describe a physically admissible macroscopic response, i.e., one that respects the principles of causality and passivity. This necessity is analogous to the need to include bianisotropic coupling to obtain a physically valid macroscopic description of the dynamic behavior of electromagnetic composites [2, 3].

By generalizing the approach of Willis [60] to account for piezoelectric constituent materials, Pernas-Salomón and Shmuel [41] have found that the dynamic response of such materials is described with constitutive relations that include effective moduli that couple the velocity and momentum of the medium to the electric fields. These generalized Willis couplings are therefore referred to as electromomentum couplings. From the viewpoint of applications, the significance of this result is twofold. First, it extends the design space of elastodynamic metamaterials beyond Willis materials to include coupling to the electromagnetic domain. Second, it provides a new avenue for mechanical wave manipulation using external electric sources.

The homogenization procedures of Willis [57, 58, 60], and in turn Pernas-Salomón and Shmuel [41], are based on ensemble averaging of the microscopic fields, which provides effective constitutive relations that are nonlocal in time and space. These relations become local in space when the wavelength is much larger than the microstructure, or when they are used to describe a single subwavelength element rather than a bulk, in which case they are termed the Milton-Briane-Willis equations [26–28]. Analysis of the effective parameters shows that the local part of the Willis coupling coefficients originates from broken inversion asymmetry [30, 48]. Recent experiments that demonstrate the local contributions to the Willis coupling were carried out in these settings, i.e., using asymmetric subwavelength structures [7, 8, 18, 21, 22, 31]. The objective of the present work is to provide an analogous evidence of a local electromomentum coupling by investigating the scattering response of an asymmetric piezoelectric element embedded in an elastic background material.

We consider Gedanken experiments where a heterogeneous piezoelectric element separates two homogeneous elastic slabs and scatter one-dimensional strain waves incident from the slabs. We calculate analytically the experimentally measurable reflection and transmission coefficients, and develop a retrieval method to extract the effective properties from these coefficients. This simplistic approach for homogenization, based on the scattering properties of a finite slab, was first developed for electromagnetic waves [37, 51], and was later adapted to acoustics [14]. As pointed out by Simovski [50], this simplistic approach has limited applicability, and its extracted effective properties often differ from the effective properties that are calculated using rigorous homogenization approaches, based on rational
field-averaging. Simovski terms the simplistic approach as heuristic, since while it is not optimal, in certain cases it is nevertheless useful for obtaining insightful approximations [21, 31]. This is particularly true in the low frequency, long-wavelength limit, and in the sequel we restrict attention to this limit.

We apply our heuristic homogenization scheme using two different homogenized models to describe the element: one that includes the electromomentum coupling, and one that neglects it. Borrowing the terminology in Refs. [3, 48], we refer to the former model as the effective model and to the latter model as the equivalent model.

We find that the properties retrieved using the effective model satisfy reciprocity and energy conservation [3, 48] and are independent of the excitation setup. By contrast, properties obtained by the equivalent model depend on the excitation setup, and violate reciprocity and energy conservation, even in the long-wavelength, low frequency limit. This discrepancy of the equivalent model stems from its inability to capture the fact that the reflection of incident plane waves has a directional phase angle that depends on the electric field. The electromomentum coupling precisely captures this phenomenon, and the inclusion of this coupling in the homogenized model renders it physically admissible. This demonstration is analogous to the analysis of Muhlestein et al. [31] for acoustic media where the authors demonstrated, both analytically and experimentally, that scattering from an asymmetric acoustic element can only be represented with physically meaningful material properties, if the Willis coupling is included in the homogenized constitutive relations. Specifically, they employed a heuristic homogenization method when considering two different homogenized models to describe the element: with- and without the Willis modulus, and found that only the former respects passivity and reciprocity.

We derive explicit low frequency expressions for effective properties using Taylor series, and find that they are independent of the number of unit cells in the element. Furthermore, the leading term in the expansions of the standard properties is a real constant that agrees with the expected value from static homogenization in the limiting decoupled case. By contrast, the leading term in the expansions of the Willis coupling and the electromomentum coupling is a pure imaginary linear function of the frequency. These observations are in agreement with the observations from the long-wavelength limit of the rigorous homogenization method [40], and thereby support the validity of the heuristic homogenization method in this limit. The expansions further show that the couplings depend on the order of the composition, and that certain compositions exhibit zero Willis coupling and finite electromomentum coupling. Interestingly, we found that the design rule for such compositions, obtained using the heuristic homogenization, also holds for infinite periodic laminates whose effective properties are obtained using the rigorous homogenization. The directional phase angle of elements with zero Willis coupling and nonzero electromomentum coupling vanishes in the short circuit configuration and appears in open circuit conditions, a feature that can be harnessed to control the directional phase change by the opening and shortening of the circuit.

The analysis is presented as follows. First, we provide in Sec. 2 a short summary of the relevant
governing equations. Section 3 presents a simple analysis of plane waves in piezoelectric media with and without the electromomentum coupling, through which we highlight its effect on the characteristic elastic impedance and phase velocity. The conceptual experiments that demonstrate this effect are described in Sec. 4, together with the calculations of the resultant scattering and retrieved properties of the two models. Section 5 provides the low frequency expansions of the effective properties. Numerical examples are then presented in Sec. 6, and the paper concludes with a summary of the work with final remarks in Sec. 7.

2 Field equations and constitutive relations

Pernas-Salomón and Shmuel [41] developed a comprehensive dynamic homogenization theory for piezoelectric composites. Here we review the equations relevant to the current work in the local, one-dimensional, source-free settings. In the absence of body forces and free charge, a one-dimensional piezoelectric inhomogeneous medium satisfies the balance equations

\[
\begin{align*}
\sigma_{,x} - p_{,t} &= 0, \\
D_{,x} &= 0,
\end{align*}
\]

(1)

for the stress \(\sigma\), momentum density \(p\), and electric displacement field \(D\), where \(x\) is the spatial coordinate. Faraday’s equation for the electric field \(E\) is satisfied by setting \(E = -\phi_{,x}\), where \(\phi\) is the electric potential. At each point, the fields of Eq. (1) are related to \(E\) (or \(\phi_{,x}\)) and the derivatives of the axial displacement \(u\) through the constitutive equations [5]

\[
\begin{pmatrix}
\sigma \\
D \\
p
\end{pmatrix}
= \begin{pmatrix}
C & B & 0 \\
B & -A & 0 \\
0 & 0 & \rho
\end{pmatrix}
\begin{pmatrix}
u_{,x} \\
\phi_{,x} \\
u_{,t}
\end{pmatrix},
\]

(2)

where \(\rho, A, B,\) and \(C\), are the mass density, and dielectric, piezoelectric, and elastic moduli, respectively, which vary in space since the medium is inhomogeneous. We clarify that attention is restricted to a reciprocal and lossless medium, such that the matrix in Eq. (2) is real and symmetric, and recall that this matrix is independent of the boundary conditions, for any homogeneous specimen that is large enough relatively to its microstructure [59]. This form of the constitutive relations is referred to as the stress-charge form, where \(A\) and \(C\) are measured under the conditions of constant strain and electric field, respectively.

With the objective of replacing the inhomogeneous medium by a homogeneous one that macroscopically behaves the same (in some appropriate sense), Pernas-Salomón and Shmuel [41] obtained the

---

1 For complete details on the theory in the general settings, see Refs. [41, 42].
2 The dielectric and piezoelectric moduli are often denoted in the literature by \(\varepsilon\) and \(e\) instead of the notation \(A\) and \(B\) used here [5, 45].
3 See Refs. [33, 60, 61] for details.
following constitutive equations for the effective fields

$$\begin{pmatrix} \sigma \\ D \\ p \end{pmatrix} = \begin{pmatrix} \tilde{C} & \tilde{B} & \tilde{S} \\ \tilde{B} & -\tilde{A} & \tilde{W} \\ \tilde{S} & \tilde{W} & \tilde{\rho} \end{pmatrix} \begin{pmatrix} u_x \\ \phi_x \\ u_t \end{pmatrix},$$

where we have used the same notation for the effective fields and the microscopic fields, while the effective properties are distinguished by overhead tilde. Notably $\tilde{S}$ and $\tilde{W}$ are the emergent Willis and electromomentum coupling constants, respectively, which appear only in the macroscopic description.

We recall that Eq. (3) is the reduced form of the general relations found in Ref. [41], when considering one-dimensional media free of sources, in the long-wavelength limit. We note that the homogenization process that lead to Eq. (3) uses ensemble averaging to define the effective fields [60, 61]; in the long-wavelength limit of a periodic medium, this averaging can be approximated by volume averaging. Using simple conceptual experiments, we will demonstrate that one must account for $\tilde{W}$ in order to obtain a physically admissible effective description of piezoelectric scatterers under dynamic loading scenarios. Such description should also respect energy conservation and reciprocity, and be independent of the boundary conditions, as the heterogeneous medium.

3 Plane wave analysis and the main idea

Before we begin with the analysis of the scattering experiments, it is instructive to analyze one-dimensional plane waves in piezoelectric Willis media, through which we can highlight the role of the cross-couplings on the elastic impedance and phase velocity. To this end, we consider a homogenized medium that is governed by Eq. (3), and examine the equation of motion after we substitute the constitutive relations for $\sigma$ and $p$ to yield

$$\tilde{C}u_{xx} + \tilde{B}\phi_{xx} - \tilde{W}\phi_{xt} - \tilde{\rho}u_{tt} = 0.$$  (4)

Note that $\tilde{S}u_{tx}$ and $\tilde{S}u_{xt}$ cancel out, in agreement with the observations of Muhlestein et al. [32] for the case when the Willis tensor is aligned with the direction of propagation. As is the case for standard piezoelectric media, further derivations depend on the form of the electric fields. We distinguish between the two cases: (i) short circuit for which $E = 0$, and (ii) open circuit for which $D = 0$. The piezoelectric analysis here extends that of Refs. [31, 32, 48] for purely acoustic Willis materials, and is related to the

---

4In periodic media, the fields have the form of a periodic function times a Bloch envelope, and then ensemble averaging is equal to averaging of the periodic part, while keeping the Bloch envelope [52, 60]. Since the envelope is unity in the long-wavelength limit, in this case the two definitions of volume- and ensemble averaging coincide.

5The contribution of the Willis coupling to the equations is retained in any other case where its polarization is not parallel or anti-parallel to the propagation direction [Eq. (2.8) therein].
3.1 Plane waves in a short circuit configuration

The condition $E = 0 \equiv -\phi, x$ simplifies Eq. (4) to the standard one-dimensional wave equation for an elastic medium with plane wave modulus $\tilde{C}$ and density $\tilde{\rho}$,

$$\tilde{C} u_{xx} - \tilde{\rho} u_{tt} = 0,$$

which is satisfied by plane wave solutions of the form $u(x, t) = U e^{i(\pm\tilde{k}_E x - \omega t)}$. This defines the phase velocity $\tilde{v}_E^2 := \tilde{C}/\tilde{\rho}$ and the wavenumber $\tilde{k}_E = \omega/\tilde{c}_E$ in the absence of electric field. In terms of these quantities, we write the characteristic elastic impedance $Z = \sigma/\tilde{u}_{tt}$ in a short circuit configuration. It immediately follows from the substitution of the plane wave form into the constitutive equation for $\sigma$ that $Z^\pm = \pm \tilde{Z}_E + \tilde{S}$, where $\tilde{Z}_E^2 := \tilde{\rho}\tilde{C}$, and the sign of the superscript for $Z$ designates the wave direction. The implication is that when $\tilde{S}$ exists, the impedance is asymmetric with respect to the propagation direction. This motivates us to follow Muhlestein et al. [31, 32] and define the asymmetry factor in the absence of electric field, $\chi_E = \tilde{S}/\tilde{Z}_E$, in order to rewrite the impedance as

$$Z^\pm = (\pm 1 + \chi_E) \tilde{Z}_E. \tag{6}$$

Equation (6) shows that the asymmetry factor $\chi_E$ in the absence of an $E$-field is the same as the asymmetry factor in Willis media without the electromomentum coupling. It has been established that the local Willis coupling of a reciprocal and passive medium is purely imaginary, and its leading term in a low frequency expansion is linear [23, 30, 34]. Accordingly, we can relate the asymmetry of $Z$ to a purely real coupling coefficient $\hat{S}$ through the relation $\hat{S} = i\omega \hat{S}$, that is asymptotically tractable, in terms of which we rewrite the impedance as [31]

$$Z^\pm = \pm \tilde{Z}_E + i\omega \hat{S}. \tag{7}$$

Eq. (7) highlights the fact that the characteristic elastic impedance is complex and changes phase angle with direction in media with local Willis coupling. Muhlestein et al. [31] linked this impedance to the scattering behavior of an acoustic asymmetric element, and related its imaginary part to the asymmetry in the reflection coefficients when plane waves are incident from opposing directions. This asymmetric response led to their observation that one must include Willis coupling in the dynamic effective properties to obtain a physically valid effective description of the asymmetric element, since $\tilde{Z}_E$ must be real and direction independent in order for $\tilde{C}$ and $\tilde{\rho}$ to satisfy reciprocity and energy conservation. The remaining

---

$^6$This actually motivates a different form for the constitutive relations, in which the stress depends on the acceleration and the momentum depends on the strain rate, see Refs. [27, 30, 42, 48].
insights needed to understand the electromomentum coupling are obtained from the comparison with the open circuit configuration, $D = 0$, considered next.

### 3.2 Plane waves in an open circuit configuration

It follows from Gauss’s law [Eq. (1)$_2$] that the electric displacement field is zero in the absence of free charge when the electrical components are in open circuit boundary conditions. We can then use the derivatives of Eq. (1)$_2$ and the constitutive relation for $D$ to obtain expressions for $\phi_{,xx}$ and $\phi_{,xt}$, to rewrite the equation of motion (4) as

$$
\left( \tilde{C} + \frac{\tilde{B}^2}{\tilde{A}} \right) u_{,xx} - \left( \tilde{\rho} + \frac{\tilde{W}^2}{\tilde{A}} \right) u_{,tt} = 0.
$$

Solutions to Eq. (8) are plane waves of the form $u(x, t) = U e^{i(\pm \tilde{k}_D x - \omega t)}$ with the wavenumber $\tilde{k}_D := \omega / \tilde{v}_D$ and the phase velocity $\tilde{v}_D := \tilde{C}_D / \tilde{\rho}_D$, where $\tilde{C}_D := \tilde{C} + \tilde{B}^2 / \tilde{A}$ and $\tilde{\rho}_D := \tilde{\rho} + \tilde{W}^2 / \tilde{A}$. This simple analysis reveals an appealing analogy between the piezoelectric effect and the electromomentum effect: the latter alters the apparent mass density in the same way that the former stiffens the apparent elastic modulus [5]. Therefore, evidence for $\tilde{W}$ can be found in a dynamic open circuit experiment that will prove that the effective phase velocity is given by $\tilde{C}_D / \tilde{\rho}_D$, not $\tilde{C}_D / \tilde{\rho}$. More insights are obtained from the analysis of the characteristic impedance and asymmetry factor. To this end, we substitute the above form for $u$ into the constitutive equation for $\sigma$, eliminate $\phi_{,x}$ using the constitutive equation for $D = 0$, and obtain

$$
\sigma = i \tilde{k}_D \tilde{C} u + i \frac{\tilde{B}^2}{\tilde{A}} u - i \omega \frac{\tilde{W} \tilde{B}}{\tilde{A}} u - i \omega \tilde{S} u.
$$

Using the definition of $\tilde{k}_D$ we find that the characteristic plane wave impedance in open circuit is

$$
Z^\pm := \frac{\sigma}{-i \omega u} = (\pm 1 + \chi_D) \tilde{Z}_D, \quad \tilde{Z}_D^2 := \tilde{\rho}_D \tilde{C}_D, \quad \chi_D := \frac{1}{\tilde{Z}_D} \left( \tilde{S} + \frac{\tilde{B}}{\tilde{A}} \tilde{W} \right),
$$

where $\tilde{Z}_D$ must be real for the constitutive properties to respect reciprocity and energy conservation. We again observe that the characteristic impedance is asymmetric in the propagation direction, however the asymmetry factor for the open circuit condition, $\chi_D$, depends on both the conventional Willis coefficient and the electromomentum coupling $\tilde{W}$. Previous works have shown that $\tilde{W}$—like $\tilde{S}$—is purely imaginary in reciprocal and conservative local media, and its leading term in a low frequency expansion is a linear function of frequency [41, 42]. Therefore, we can relate the asymmetry in $Z$ with a purely real coupling coefficient$^7$ that is asymptotically tractable, say $\tilde{W}$, through the relation $\tilde{W} = i \omega \tilde{W}$, in terms of which

---

$^7$This motivates a different form for the constitutive relations, in which the electric displacement field depends on the acceleration and the momentum depends on the time rate of the electric field, see Ref. [42].
we rewrite the impedance as

\[ Z^\pm = \pm \tilde{Z}_D + i\omega \left( \hat{S} + \frac{\tilde{B}}{A} \tilde{W} \right). \]  

Equation (11) indicates that the electromomentum coefficient alters the directional dependence by altering the phase angle in addition to the \( \hat{S} \) contribution. This suggests a simple test for the existence of \( \tilde{W} \): Examine the directional phase change of waves that are reflected from an asymmetric piezoelectric element in scattering experiments, both in short and open circuit configurations; if they do not match, it will provide evidence that \( \tilde{W} \) is non-zero and must be considered in order to determine physically meaningful effective properties of the medium. This is precisely what we demonstrate in the sections that follow by extending the scheme of Muhlestein et al. [31] to piezoelectric media.

4 Scattering from a piezoelectric Willis element

Consider a piezoelectric stack connecting two semi-infinite slabs made of an elastic isotropic material with plane wave modulus \( C_0 \) and density \( \rho_0 \). The piezoelectric stack comprises three layers, 1, 2 and 3, of lengths \( l_1, l_2 \) and \( l_3 \), respectively, as shown in Fig. 1. Thin electrodes are located at the interfaces between the stack and the elastic slabs. Having setting up the Gedanken experimental apparatus, we conduct a scattering analysis, from which we analytically determine the transmission and reflection coefficients of the piezoelectric stack. We will use these coefficients in an inverse program to determine the effective properties of a fictitious homogenized medium that reproduces the same scattering that the heterogeneous stack generates [14, 31, 53]. The retrieved effective properties of the homogenized medium depend on the model chosen for its constitutive relations. It is important to note that while the analysis that follows considered a single, heterogeneous scatterer, which can also be understood as a unit cell from the perspective of polarizability [2, 22, 44, 48, 53], the approach employed here is representative of experimental methods used to characterized material properties and can be extended to consider the response of many unit cells [31]. In this section we describe a scheme to retrieve the effective properties based on two homogenized models: one that includes the electromomentum coupling [Eq. (3)], and one equivalent model that neglects it. We will show that while the latter model delivers (by construction) the same scattering coefficients as our effective model (hence the term equivalent), the resulting properties violate reciprocity and energy conservation and therefore lack physical meaning. Further, the properties retrieved using the equivalent model depend on the excitation setup, even in the low frequency limit.

4.1 Retrieved properties from short circuit conditions

Consider a setup where the two electrodes at the ends of the piezoelectric stack are connected in a short circuit configuration (switch is closed in Fig. 1), such that the average (or effective) electric field is null.
FIG. 1: Schematics of the Gedanken experiments on a piezoelectric element covered by electrodes at $x_0$ and $x_3$. The element is made of three layers which connect two semi-infinite elastic slabs made of an isotropic material with plane wave modulus $C_0$ and density $\rho_0$. When the switch is closed (figures in the left column) and open (figures in the right column), the setup corresponds to short- and open-circuit electric boundary conditions, respectively. For each setup we analyze an experiment where the incident waves are incoming from the left waveguide (figures at the top row), and an experiment where the incident waves are incoming from the right waveguide (figures at the bottom row). Incident, transmitted and reflected waves are denoted by light blue, green and red arrows. The phase of the reflected waves depends on the direction of the incoming waves and the electric circuit conditions. This dependency is captured by the electromomentum coupling.

Two experiments are considered in this configuration: in experiment L (resp. R), the stack is excited a time-harmonic longitudinal wave that is incoming from the left slab (resp. right). The incident wave is partly reflected at the interface with the stack and partly transmitted to the opposite slab. We assume a time dependency $e^{-i\omega t}$ and write the resultant displacement field in the elastic slabs as

$$u(x, t) = \begin{cases} \langle c_L^+ e^{ik_0 x} + c_L^- e^{-ik_0 x} \rangle e^{-i\omega t}, & x \leq x_0, \\ \langle c_R^+ e^{ik_0 x} + c_R^- e^{-ik_0 x} \rangle e^{-i\omega t}, & x \geq x_3, \end{cases}$$

where $c_L^+$ (resp. $c_R^-$) is the prescribed amplitude of the incident wave in experiment L (resp. R), and $c_R^+$ (resp. $c_L^-$) is zero. These experimentally measurable coefficients can be calculated analytically by introducing the state vector $h(x)^8$ that is continuous in $x$,

$$h(x) = (u, \phi, \sigma, D)^T.$$  

\[ k_0 = \omega \sqrt{\frac{\rho_0}{C_0}} \]

where $c_L^+$ (resp. $c_R^-$) is the prescribed amplitude of the incident wave in experiment L (resp. R), and $c_R^+$ (resp. $c_L^-$) is zero. These experimentally measurable coefficients can be calculated analytically by introducing the state vector $h(x)^8$ that is continuous in $x$,

$$h(x) = (u, \phi, \sigma, D)^T.$$  

\[ k_0 = \omega \sqrt{\frac{\rho_0}{C_0}} \]  

\[ 8 \text{ Henceforth, with an abuse of notation, we omit the dependency on } t, \text{ and recall that it is always in the form } e^{-i\omega t}. \]
The values of \( h(x) \) at the ends \( x_{n-1} \) and \( x_n \) of the \( n^{th} \) piezoelectric layer are related via [19]

\[
h(x_n) = T_{n}^\emph{em} h(x_{n-1}), \quad T_{n}^\emph{em} = \begin{pmatrix}
\cos k_D n l_n & 0 & \sin k_D n l_n / \omega Z_D n & \frac{B_n}{A_n} \sin k_D n l_n / \omega Z_D n \\
\frac{B_n}{A_n} (\cos k_D n l_n - 1) & 1 & \frac{B_n}{A_n} \sin k_D n l_n / \omega Z_D n & \frac{B_n}{A_n} \cos k_D n l_n - \frac{L_n}{A_n} \\
-\omega Z_D n \sin k_D n l_n & 0 & \cos k_D n l_n & 1 \\
0 & 0 & 0 & 0
\end{pmatrix},
\]

where \( k_D n = \omega \sqrt{\rho_n / C_D n} \), \( Z_D n = \sqrt{\rho_n C_D n} \) and \( C_D n = (C_n + B_n^2 / A_n) \). Continuity of \( h(x) \) implies that

\[
h(x_3) = T^L h(x_0), \quad T^L = T_3^\emph{em} T_2^\emph{em} T_1^\emph{em},
\]

in experiment L, while in experiment R, the composition order of \( T_{n}^\emph{em} \) is reversed. We focus first on experiment L. In this case, it follows from Eq. (15) that

\[
\phi(x_3) - \phi(x_0) = T_{21}^L u(x_0) + T_{23}^L \sigma(x_0) + T_{24}^L D,
\]

where \( T_{ij}^L \) is the \( ij \)-component of the matrix \( T^L \), and we have used the fact that electric displacement is constant inside the stack. Since the electrodes are in short circuit such that the potential difference is zero, i.e., \( \phi(x_3) - \phi(x_0) = 0 \), then Eq. (16) together with Eq. (15) implies

\[
\begin{pmatrix}
u(x_3) \\
\sigma(x_3)
\end{pmatrix} = T^s(x_3, x_0) \begin{pmatrix}
u(x_0) \\
\sigma(x_0)
\end{pmatrix}, \quad T^s = \begin{pmatrix}
T_{11}^L & -T_{14}^L & T_{13}^L - T_{14}^L T_{23}^L \\
T_{31}^L & -T_{34}^L & T_{33}^L - T_{34}^L T_{23}^L
\end{pmatrix}.
\]

Equation (17) relates the displacement and stress at the two ends of the stack, and hence the amplitudes of the incoming and outgoing waves. By applying the continuity conditions for the displacement and stress fields at \( x_0 \) and \( x_3 \) and using Eqs. (12) and (17), we relate the amplitudes of the waves through the following coefficients transfer matrix

\[
\begin{pmatrix}
c_R^+ \\
-c_R^-
\end{pmatrix} = K^s(R, L) \begin{pmatrix}
c_L^+ \\
-c_L^-
\end{pmatrix},
\]

where

\[
K^s(R, L) = Q_0(x_3)^{-1} T^s(x_3, x_0) Q_0(x_0), \quad Q_0(x) = \begin{pmatrix}
e^{ik_0 x} & e^{-ik_0 x} \\
iC_0 k_0 e^{ik_0 x} & -iC_0 k_0 e^{-ik_0 x}
\end{pmatrix}.
\]
Equation (18) returns the output of experiment L when \( c^{-} = 0 \) with the reflection and transmission amplitudes \( r_L = c_L^- / c_L^+ \) and \( t_L = c_L^+ / c_L^+ \), respectively. Similarly, Eq. (18) returns the output of experiment R using \( c_L^+ = 0 \) with the reflection and transmission amplitudes \( r_R = c_R^+ / c_R^- \) and \( t_R = c_R^- / c_R^- \), respectively.

The matrix \( K^e \) can be expressed in terms of these amplitudes [38], namely,

\[
K^e(R, L) = \begin{pmatrix}
t_L - r_R t_R^{-1} r_L & r_R t_R^{-1} \\
-r_L t_R^{-1} & t_R^{-1}
\end{pmatrix}.
\] (20)

Equations (17)-(20) together imply the L-experimental results

\[
t_L = 2e^{-ik_0l} \left( T_{s_{22}}^L + T_{s_{11}}^L - i\omega Z_0 T_{s_{12}}^L - (i\omega Z_0)^{-1} T_{s_{21}}^L \right)^{-1},
\] (21a)

\[
r_L = \left( T_{s_{22}}^L - T_{s_{11}}^L - i\omega Z_0 T_{s_{12}}^L + (i\omega Z_0)^{-1} T_{s_{21}}^L \right) \frac{t_L}{2}.
\] (21b)

The analysis for experiment R mirrors the above procedure, showing that \( r_R \) and \( t_R \) equal, respectively, the right hand sides of Eqs. (21b) and (21a), after replacing \( T_{s_{ij}}^L \) by \( T_{s_{ij}}^R \). Notably, we find \( t_L \equiv t_R \), as expected for a reciprocal medium, while the phase of \( r_L \) may differ from the phase of \( r_R \). This difference depends on the spatial asymmetry of the stack, and is a manifestation of the directional dependency of the effective characteristic impedance, as discussed in Sec. 3.1.

The objective now is to determine the properties of a fictitious homogeneous medium that exhibits the same scattering coefficients as the stack, i.e., will reproduce the same \( K^e(R, L) \)—under the same boundary conditions. As per this short circuit configuration, the electric field in the fictitious homogeneous medium should vanish, like the average electric field in the stack. The constitutive relations for \( \sigma \) and \( p \) of both the effective and equivalent models reduce to

\[
\sigma = \tilde{C} u_{,x} - i\omega \tilde{S} u,
\] (22a)

\[
p = \tilde{S}^\dagger u_{,x} - i\omega \tilde{\rho} u.
\] (22b)

(Later on, we will use superscript \( \text{eq} \) to distinguish the retrieved properties of the equivalent model that neglects \( \tilde{W} \) from the retrieved properties of the effective that includes \( \tilde{W} \)). In this case, the constitutive equations for \( \sigma \) and \( p \) [Eq. (22)] involve only the effective mechanical properties and thus reduce to the Willis form, in agreement with the analysis provided in Sec. 3.1.

We note that unlike in Eq. (3), Eq. (22b) does not assume \( \text{a priori} \) that the conditions imposed by reciprocity are satisfied [30, 42], which would imply that the coupling between \( \sigma \) and \( u_{,t} \) is equal to the coupling between \( p \) and \( u_{,x} \). To maintain the additional generality, we denote by \( \tilde{S}^\dagger \) the coefficient that couples \( p \) with \( u_{,x} \), and show by analysis that \( \tilde{S} = \tilde{S}^\dagger \). Before we proceed to determine \( \tilde{C}, \tilde{\rho}, \tilde{S} \) and \( \tilde{S}^\dagger \), we emphasize that the remaining constitutive equation for the electric displacement field depends on the form of the chosen model, i.e., whether or not it accounts for the electromomentum coupling. This will
be addressed in Sec. 4.2.

To determine the properties $\tilde{C}$, $\tilde{\rho}$, $\tilde{S}$ and $\tilde{S}^\dagger$ of a fictitious homogenized medium with the same scattering response as the stack, we relate the displacement and stress fields at the ends of the homogenized medium via (Appendix A)

$$
\begin{pmatrix}
  u(x_3) \\
  \sigma(x_3)
\end{pmatrix} = T^m(x_3, x_0) \begin{pmatrix}
  u(x_0) \\
  \sigma(x_0)
\end{pmatrix},
$$

(23)

where $T^m(x_3, x_0) = e^{iM}$ is the transfer matrix of the homogenized medium, defined by

$$
M = \begin{pmatrix}
  i\omega \tilde{S} \tilde{C}^{-1} & \tilde{C}^{-1} \\
  \omega^2 \tilde{S} \tilde{S}^\dagger \tilde{C}^{-1} - \omega^2 \tilde{\rho} & -i\omega \tilde{S}^\dagger \tilde{C}^{-1}
\end{pmatrix}.
$$

(24)

We require that the homogenized medium reproduces the same scattering properties, i.e., the same $K^s$. This implies that the variables in Eq. (24) are determined from [see Eqs. (19)-(20)]

$$
Q_0^{-1}(x_3) T^m Q_0(x_0) = \begin{pmatrix}
  t_L - r_R t_R^{-1} r_L & r_R t_R^{-1} \\
  -r_L t_R^{-1} & t_R^{-1}
\end{pmatrix},
$$

(25)

which yield equations for $T^m$ in terms of the reflection and transmission coefficients $r_L, r_R, t_L$ and $t_R$. Recalling $t_L \equiv t_R = t$, simplifies $T^m$ to

$$
T^m = \frac{1}{2t} \left( \begin{array}{cc}
  \vartheta e^{ik_0l} + e^{-ik_0l} + r_R - r_L & \frac{1}{i\omega Z_0} \left[ \vartheta e^{ik_0l} - e^{-ik_0l} - r_R - r_L \right] \\
  i\omega Z_0 \left[ \vartheta e^{ik_0l} - e^{-ik_0l} + r_R + r_L \right] & \vartheta e^{ik_0l} + e^{-ik_0l} - r_R + r_L
\end{array} \right),
$$

(26)

where $\vartheta = t^2 - r_L r_R$, and $Z_0 = \sqrt{\rho_0 C_0}$ is the characteristic impedance of the elastic slabs. By applying Sylvester’s formula to the logarithm of $T^m$, Eq. (26) admits the following simplification [15, 46, 47]

$$
M = \frac{\psi}{l \sin \psi} \left( T^m - \frac{1}{2} \text{tr} T^m \right), \quad \cos \psi = \frac{1}{2} \text{tr} T^m = \frac{\vartheta e^{ik_0l} + e^{-ik_0l}}{2t},
$$

(27)

where $e^{\pm i\psi}$ are the eigenvalues of $T^m$. We deduce from Eq. (27) that $M_{22} = -M_{11}$, and the effective
where, as mentioned, in this setup the elastic equivalent properties are equal to the elastic effective properties. Equation (28) expresses the effective properties directly in terms of the experimentally measurable scattering coefficients [which were analytically calculated using Eq. (21)]. Thus, by construction, the retrieved models deliver the same scattering response that the piezoelectric stack produces. The above experiments are consistent with the conditions that are required to evaluate the properties of a standard piezoelectric material in the stress-charge form, in the sense that the stiffness was evaluated at a prescribed (effective) electric field.

To summarize the results of our Gedanken experiments so far: we find frequency-dependent effective properties, even though the assumed properties of each constituent are frequency-independent. Notably, the Willis couplings $\tilde{S}$ and $\tilde{S}^\dagger$ are equal one to another and depend on the spatial asymmetry of the stack through $r_R - r_L$. If the stack has certain symmetry properties, then the reflection of incoming waves from the right is the same as from the left and the Willis couplings vanish, as we will explicitly show later using low frequency approximations for the dynamic effective properties.

4.1.1 First inconsistency in retrieving the piezoelectric coefficient when neglecting $\tilde{W}$

A different perspective on the retrieval process is to consider the retrieved properties as those that relate the effective fields in the piezoelectric element. In the low frequency, long-wavelength limit, the effective fields are defined as the volume average of the microscopic fields. Evaluating the volume averages over the constitutive relations for $\sigma$ and $p$ deliver equations for $\tilde{\rho}$, $\tilde{C}$ and $\tilde{S}$ that are consistent with Eq. (28a). The third equation for $D$, namely,

$$\langle D \rangle = \tilde{B} \langle u, x \rangle - i\omega \tilde{W} \langle u \rangle, \quad (29)$$

is not sufficient to determine $\tilde{B}$ and $\tilde{W}$. If we ignore the electromomentum effect, i.e., we assume that the effective electric displacement is independent of the effective velocity field, then this experiment is sufficient to determine the equivalent piezoelectric coefficient $\tilde{B}^{\text{eq}}$ from the average fields. Specifically,
an additional equation $\tilde{B}^{eq}$ is obtained from the requirement that the equivalent properties of the homogenized model deliver the same average fields\(^9\) that are generated in the piezoelectric stack. Thus, when $\tilde{W}$ is neglected in Eq. (3), the equivalent piezoelectric coefficient is determined from the relationship

$$\langle D \rangle = \tilde{B}^{eq} \langle u, x \rangle, \text{ so } \tilde{B}^{eq} := \frac{\langle D \rangle}{\langle u, x \rangle},$$

(30)

where $\langle \rangle$ denotes volume averaging over $x_0 \leq x \leq x_3$. Now, if $\tilde{B}^{eq}$ is to satisfy energy conservation and reciprocity, in the long-wavelength limit it should be a real-valued quantity that is independent of the direction of the wave. Stating explicitly the implication of the latter condition to our analysis, it requires that $\tilde{B}^{eq}_L := \langle D \rangle / \langle u, x \rangle_L$ will be equal to $\tilde{B}^{eq}_R := \langle D \rangle / \langle u, x \rangle_R$, where we recall that subscripts L and R correspond to fields that are generated in the left ($c^+_L = 1, c^-_R = 0$) and right ($c^+_L = 0, c^-_R = 1$) experiments. However, using Eq. (16) to determine $\langle D \rangle_\alpha$ and Eq. (12) to express $\langle u, x \rangle_\alpha$ in terms of the scattering coefficients, we find that

$$\tilde{B}^{eq}_\alpha = \frac{l \left[ T_{21}^\alpha + i \omega Z_0 T_{23}^\alpha + r_\alpha e^{i k_0 l} (T_{21}^\alpha - i \omega Z_0 T_{23}^\alpha) \right]}{(1 + (r_\alpha - t)e^{i k_0 l}) T_{24}^\alpha}, \ \alpha = L, R,$$

(31)

implying that $\tilde{B}^{eq}_L \neq \tilde{B}^{eq}_R$ and moreover $\text{Im}[\tilde{B}^{eq}_\alpha] \neq 0$. These nonphysical artifacts are generated when neglecting the electromomentum effect and persist in the low frequency limit, as we will demonstrate in Sec. 6.

Before we proceed to analyze the open circuit configuration, we summarize the results from the short circuit configuration. We have calculated the reflection and transmission coefficients for incidence from both sides of the heterogeneous scatterer. In terms of these coefficients we have estimated the effective short circuit dynamic stiffness, $\tilde{C}$, the short circuit dynamic density $\tilde{\rho}$, and the Willis coupling, $\tilde{S}$. We have demonstrated that neglecting electromomentum coupling leads to estimates for the piezoelectric coefficient that violate reciprocity and energy conservation (if the scatterer is asymmetric).

The equations that the short circuit configuration provide do not allow the extraction of the electromomentum coefficient and the dynamic effective dielectric permittivity; these will be determined using scattering experiments on the heterogeneous scatterer in the open circuit configuration. The open circuit configuration will also demonstrate that the retrieved properties using the equivalent description are inconsistent as they depend on the electric boundary conditions, even in the long-wavelength limit. This observation further reinforces the necessity of including electromomentum coupling in heterogeneous piezoelectric media with subwavelength-scale asymmetry.

\[^9\]Again, we recall that the use of volume averages instead of ensemble averages is valid only in the long-wavelength, low frequency regime.
4.2 Retrieved properties from an open circuit experiment

Consider next the same scattering problems as in Sec. 4.1, only now the stack is in an open circuit configuration, i.e., the switch is open in Fig. 1. We repeat the same analysis described in Sec. 4.1 now accounting for \( D = 0 \). The objective is to retrieve the homogenized material properties in terms of the reflection and transmission coefficients in open circuit conditions, now denoted by \( r_{Lo}, r_{Ro}, t_{o} \). Accordingly, we modify Eq. (15) when considering a null \( D \)-field, and obtain [cf. Eq. (17)]

\[
\begin{pmatrix}
  u(x_3) \\
  \sigma(x_3)
\end{pmatrix} = T^o \begin{pmatrix}
  u(x_0) \\
  \sigma(x_0)
\end{pmatrix}, \quad T^o = \begin{pmatrix}
  T^L_{11} & T^L_{13} \\
  T^L_{31} & T^L_{33}
\end{pmatrix}. \tag{32}
\]

We relate the transfer matrix \( T^o \) to the reflection and transmission coefficients according to Eqs. (19)-(21) and find that for experiment L the coefficients \( r_{Lo} \) and \( t_{Lo} \) satisfy Eqs. (21b) and (21a) when \( T^o \) replaces \( T^s \). The analysis for experiment R mirrors the procedure described above, showing that \( r_{Ro} \) and \( t_{Ro} \) equal, respectively, to the right-hand side of Eqs. (21b) and (21a), where \( T^o \left(T^L\right) \) is replaced by \( T^o \left(T^R\right) \). It is clear that the scattering coefficients in this experiment are different from the coefficients in the short circuit experiment, in view of the difference between \( T^o \) and \( T^s \). Again, we find that \( t_{Lo} \equiv t_{Ro} \), as it should, while \( r_{Lo} \) and \( r_{Ro} \) differ by a phase.

As in Sec. 4.1, we require the properties of the fictitious homogeneous medium to exhibit the same scattering coefficients as the stack when subjected to the same electrical boundary conditions. We will develop the equations using the effective model, and recall that the equations for the equivalent model are obtained by setting \( \tilde{W} = 0 \). Since we consider here an open circuit configuration, the \( D \)-field in the fictitious homogeneous medium is null, and hence its constitutive equation for \( D \) provides the relation

\[
\phi_{,x} = \tilde{A}^{-1} \left( \tilde{B} u_{,x} - i \omega \tilde{W} u \right). \tag{33}
\]

Subsequently, we employ this relation to replace \( \phi_{,x} \) in the constitutive relations for \( \sigma \) and \( p \), which now read

\[
\sigma = \left( \tilde{C} + \tilde{B}^2 \right) u_{,x} - i \omega \left( \tilde{S} + \frac{\tilde{B}}{\tilde{A}} \tilde{W} \right) u, \tag{34a}
\]

\[
p = \left( \tilde{S}^\dagger + \frac{\tilde{B}}{\tilde{A}} \tilde{W}^\dagger \right) u_{,x} - i \omega \left( \tilde{\rho} + \frac{\tilde{W} \tilde{W}^\dagger}{\tilde{A}} \right) u. \tag{34b}
\]

Finally, we repeat Eqs. (23)-(25) using the transfer matrix that is based on Eq. (34), and denote its logarithm by \( M^o \). The resultant relationships for the effective dynamic properties are
the equivalent properties \( \tilde{S} \) in the fully coupled medium. We first observe that Eq. (35b) implies that the electromomentum coupling contributes to the asymmetry in the reflection, since Eq. (28) and Eq. (35a) provide different values for the foregoing properties. If we denote equivalent properties that are extracted from short- and open circuit conditions by subscript \( s \) and \( o \), respectively, then \( \tilde{S}^{eq}_s \neq \tilde{S}^{eq}_o \). This type of dependency of the retrieved properties of inappropriate models on the experimental setup was noted before in Refs. [2, 48].

Equation (35) explicitly illustrates the electromomentum scattering contribution to the extracted effective properties. Equation (35a) shows that the electromomentum coupling contributes to the asymmetry in the reflection, in addition to the asymmetry associated with the Willis coefficient, \( \tilde{S} \). Further, Eq. (35d) shows that the presence of electromomentum coupling modifies the apparent effective dynamic mass density. These phenomena are in agreement with the analysis in Sec. 3.

The above analysis was based on the effective model that includes \( \tilde{W} \). The procedure to retrieve the homogenized properties using the equivalent model is the same up to setting \( \tilde{W} = 0 \). Accordingly, the equivalent properties \( \tilde{S}^{eq}_s, \tilde{S}^{eq}_o \) and \( \tilde{\rho}^{eq} \) equal to the right-hand side of Eqs. (35a), (35b) and (35d), respectively. This results in a secondary inconsistency in the model that neglects the electromomentum coupling: the equivalent properties depend on the electrical boundary conditions, since Eq. (28) and Eq. (35) provide different values for the foregoing properties. If we denote equivalent properties that are extracted from short- and open circuit conditions by subscript \( s \) and \( o \), respectively, then \( \tilde{S}^{eq}_s \neq \tilde{S}^{eq}_o \). This type of dependency of the retrieved properties of inappropriate models on the experimental setup was noted before in Refs. [2, 48].

Having pointed out the second inconsistency in the equivalent model which reinforces the need to include electromomentum coupling, we proceed to determine the effective electromechanical properties in the fully coupled medium. We first observe that Eq. (35b) implies

\[
\tilde{W} = \tilde{W}^\dagger,
\]

where we used the fact that \( \tilde{S} \equiv \tilde{S}^\dagger \) from Eq. (28b). While there are three additional equations in Eq. (35), the remaining three coefficients (\( \tilde{A}, \tilde{B} \) and \( \tilde{W} \)) cannot be determined uniquely, since they enter the equations as products. Therefore, one more independent equation is required, which is obtained from the condition on the spatial average of the constitutive equation for \( D \) (cf. Sec. 4.1.1):

\[
\tilde{S} + \frac{\tilde{B}}{A} \tilde{W} = \frac{M_{11}^o}{i\omega M_{12}^o} = \frac{Z_0 (r_{Ro} - r_{Lo})}{(t_o^2 - r_{Lo} r_{Ro}) e^{ik_{d}l} - e^{-ik_{d}l} - r_{Ro} - r_{Lo}}, \tag{35a}
\]

\[
\tilde{S}^\dagger + \frac{\tilde{B}}{A} \tilde{W}^\dagger = -\frac{M_{22}^o}{i\omega M_{12}^o} \equiv \tilde{S} + \frac{\tilde{B}}{A} \tilde{W}, \tag{35b}
\]

\[
\tilde{C} + \frac{\tilde{B}^2}{A} = M_{12}^{o - 1} = \frac{2i\omega Z_0 l t_o \psi_o^{-1} \sin \psi_o}{(t_o^2 - r_{Lo} r_{Ro}) e^{ik_{d}l} - e^{-ik_{d}l} - r_{Ro} - r_{Lo}}, \tag{35c}
\]

\[
\tilde{\rho} + \frac{\tilde{W} \tilde{W}^\dagger}{A} = \frac{\det M^o}{\omega^2 M_{12}^o} = \frac{-i\rho_0 \psi_o}{2t_o k_0 l \sin \psi_o} \left[ \left( \frac{(t_o^2 - r_{Lo} r_{Ro}) e^{ik_{d}l} - e^{-ik_{d}l}}{(t_o^2 - r_{Lo} r_{Ro}) e^{ik_{d}l} - e^{-ik_{d}l} - r_{Ro} - r_{Lo}} \right)^2 - 4r_{Ro} r_{Lo} \right], \tag{35d}
\]

where

\[
\cos \psi^o = \frac{(t_o^2 - r_{Lo} r_{Ro}) e^{ik_{d}l} + e^{-ik_{d}l}}{2t_o}. \tag{36}
\]
$0 = \tilde{B} \langle u_x \rangle - \tilde{A} \langle \phi_x \rangle - i\omega \tilde{W} \langle u \rangle.$  

(38)

[Alternatively, as the third equation it is possible to use the corresponding equation from the short circuit experiment, namely, Eq. (29). In fact, we use Eq. (29) as a consistency check for the effective properties to be independent of the experimental setup.]

Having at hand the solutions for the field variables $u$ and $\phi$, we use Eq. (38) together with Eq. (35) to obtain expressions for the rest of the effective properties. We omit these lengthy expressions here, and analyze their low frequency expansions in Sec. 5. Before doing so, we emphasize that there are two assumptions in the procedure described above. (i) We assume that the effective properties relate volume averages instead of ensemble averages; (ii) We assume that the retrieved quantities—which depend on the surface data—indeed characterize the effective properties. These assumptions are valid only in the low frequency, long-wavelength ($\tilde{kl} \ll 1$) regime [31, 49]. In this regime, the effective properties that result from the process are independent of the experimental setup, i.e., independent of the electrical boundary conditions. By contrast, the equivalent properties depend on these conditions, even in the low frequency, long-wavelength limit. We have validated the consistency of the effective model by comparing the effective properties computed here with the effective properties that are calculated from another electrical setup. In this third setup, the piezoelectric element is subjected to a time harmonic voltage drop, while its boundaries are kept clamped (see analysis in Appendix B). In the next section, we provide the low frequency approximations of the effective properties using Taylor expansions. As per the discussion above, the leading terms in these expansions for the effective properties are independent of the experimental setup.

5 Low frequency approximations

5.1 Peano expansion

To derive explicit expressions in the low frequency, long-wavelength limit, it proves useful to first analyze the reflection and transmission coefficients. To this end, we use the Peano expansion [16] for the transfer matrix of the layers

\[
\mathbf{T}^\alpha = I_{4 \times 4} + l \langle \mathbf{M} \rangle + \mathcal{O}(\omega^2), \quad \mathbf{M}_n = \begin{pmatrix} 0 & 0 & C_n^{-1} & B_n \\ 0 & 0 & -\frac{B_n}{A_n C_n} & \frac{B_n}{A_n C_n} \\ -\rho_n \omega^2 & 0 & 0 & 0 \\ 0 & 0 & 0 & 0 \end{pmatrix},
\]

(39)
where we recall that \( \alpha \) denotes the direction of the incident waves, and note that the terms of order \( \omega^2 \) depend on this direction. Using this expression in Eq. (21) provides the following power series expansions for the coefficients in the short circuit experiment:

\[
r_R \approx r_L = \frac{ik_0 l}{2} \left[ \rho_0^{-1} \langle \rho \rangle - C_0 \left( \langle C_D^{-1} \rangle + \gamma \langle \frac{B}{AC_D} \rangle \right) \right] + \mathcal{O} (\omega^2), \quad \gamma = \langle \frac{B}{AC_D} \rangle \langle \frac{C}{AC_D} \rangle^{-1} \tag{40a}
\]

\[
r_L - r_R = \omega^2 \sum_{p=1}^{2} \sum_{q=p+1}^{2} \frac{L_p l_q}{D_p D_q} \left[ \Delta_{qp} \left( Z_D^2 \right) + \gamma \frac{B_p B_q}{A_p A_q} \Delta_{qp} \left( \frac{A}{B} Z_D^2 \right) \right] + \mathcal{O} (\omega^3), \tag{40b}
\]

\[
t = 1 + \frac{ik_0 l}{2} \left[ \rho_0^{-1} \langle \rho \rangle + C_0 \left( \langle C_D^{-1} \rangle + \gamma \langle \frac{B}{AC_D} \rangle \right) - 2 \right] + \mathcal{O} (\omega^2), \tag{40c}
\]

where \( \Delta_{qp} f := f_p - f_q \) is the difference between the value of \( f \) in layer \( p \) and layer \( q \). Carrying out the same procedure for the coefficients of the open circuit experiment shows that the coefficients have the same form as in Eq. (40), only now the terms that involve products with \( \gamma \) do not appear. Equation (40b) shows that the leading term in the difference between the right- and left reflection coefficients is of order \( \omega^2 \), and depends on the asymmetry in the electromechanical properties of the scatterer.

### 5.2 Explicit low frequency expressions

Using the expression for the transmission and reflection coefficients, we derive the Taylor expansion\(^{10}\) of the effective properties [Eqs. (28), (B.10) and (B.13)] about \( \omega = 0 \). After some rearrangement of terms we obtain

\[
\tilde{\rho} = \langle \rho \rangle + \mathcal{O} (\omega^2), \tag{41a}
\]

\[
\tilde{C} = \left[ \langle C_D^{-1} \rangle + \gamma \langle \frac{B}{AC_D} \rangle \right]^{-1} + \mathcal{O} (\omega^2), \quad \text{where} \quad \gamma = \langle \frac{B}{AC_D} \rangle \langle \frac{C}{AC_D} \rangle^{-1}, \tag{41b}
\]

\[
\tilde{A} = \left[ \langle A^{-1} \rangle - \left( \langle B^2 \rangle \langle A^2 \rangle \right) + \langle C_D^{-1} \rangle^{-1} \left( \langle B \rangle \langle C_D \rangle \right) \right]^{-1} + \mathcal{O} (\omega^2), \tag{41c}
\]

\[
\tilde{B} = \langle \frac{B}{AC_D} \rangle \left[ \langle A^{-1} \rangle \langle C_D^{-1} \rangle - t^{-2} \sum_{p=1}^{2} \sum_{q=p+1}^{2} \frac{L_p l_q}{D_p D_q} \left( \Delta_{qp} \left( \frac{B}{A} \right) \right)^2 \right]^{-1} + \mathcal{O} (\omega^2), \tag{41d}
\]

\[
\tilde{S} = \frac{i \omega}{2 t} \tilde{C} \sum_{p=1}^{2} \sum_{q=p+1}^{2} \frac{L_p l_q}{D_p D_q} \left[ \Delta_{qp} \left( Z_D^2 \right) + \gamma \frac{B_p B_q}{A_p A_q} \Delta_{qp} \left( \frac{A}{B} Z_D^2 \right) \right] + \mathcal{O} (\omega^2), \tag{41e}
\]

\[
\tilde{W} = \frac{i \omega}{2 t^2} \frac{\tilde{B}}{\langle \frac{B}{AC_D} \rangle} \sum_{p=1}^{2} \sum_{q=p+1}^{2} \frac{L_p l_q}{D_p D_q} \Delta_{qp} \left( \frac{B}{A} \right) \sum_{r=p}^{q} \rho_r l_r \left( 2 - \delta_{pr} - \delta_{qr} \right) + \mathcal{O} (\omega^2), \tag{41f}
\]

\(^{10}\)We used Wolfram Mathematica Series function.
where \( \delta_{pr} = 1 \) if \( p = r \), and zero otherwise. We observe that the leading term of all the effective properties except \( \tilde{S} \) and \( \tilde{W} \) is independent of \( \omega \) and the ordering of the layers. These terms agree with their expected values from static homogenization in the limiting decoupled case. Thus, the mass density reduces to the arithmetic mean, while when \( B = 0 \) the stiffness and the permittivity reduce to the harmonic mean.

In contrast, the leading term in the expansions of the Willis coupling and the electromomentum coupling is pure imaginary and linear in \( \omega \). Furthermore it depends on the ordering of the layers, such that \( \tilde{S} \) and \( \tilde{W} \) flip sign when layers 1 and 3 are interchanged. Since these couplings capture the reflection asymmetry, they inherit the dependency on the asymmetry in the electromechanical properties of the scatterer that Eq. (40b) exhibits. We also note that Eq. (40b) can be manipulated to a form that depends explicitly on \( Z_E \) and \( \rho B \) of each layer, with which \( \tilde{S} \) can be written as

\[
\tilde{S} = \frac{i \omega}{2l} \left\{ l_1 l_2 \left[ \alpha_3 \Delta_{21}(Z_E^2) + \beta_3 \Delta_{21}(B \rho) + \frac{A_2 B_1 l_3}{\rho_3} (B_1 \rho_1 C_3 \rho_3 - B_3 \rho_3 C_2 \rho_2) + \frac{A_1 B_2 l_3}{\rho_3} (B_3 \rho_3 C_1 \rho_1 - B_2 \rho_2 C_3 \rho_3) \right] + l_1 l_3 \left[ \alpha_2 \Delta_{31}(Z_E^2) + \beta_2 \Delta_{31}(B \rho) + \frac{A_3 B_1 l_2}{\rho_2} (B_1 \rho_1 C_2 \rho_2 - B_2 \rho_2 C_3 \rho_3) + \frac{A_1 B_3 l_2}{\rho_2} (B_2 \rho_2 C_1 \rho_1 - B_3 \rho_3 C_2 \rho_2) \right] + l_2 l_3 \left[ \alpha_1 \Delta_{32}(Z_E^2) + \beta_1 \Delta_{32}(B \rho) + \frac{A_3 B_2 l_1}{\rho_1} (B_2 \rho_2 C_1 \rho_1 - B_1 \rho_1 C_3 \rho_3) + \frac{A_2 B_3 l_1}{\rho_1} (B_1 \rho_1 C_2 \rho_2 - B_3 \rho_3 C_1 \rho_1) \right] \right\} + O(\omega^2), \tag{42}
\]

with some property-dependent constants \( \{ \chi, \alpha_j, \beta_j, j = 1, 2, 3 \} \) that are given in Appendix C. Equation (42) explicitly shows that \( \tilde{S} \) depends on the asymmetry in the elastic impedance \( Z_E^2 = \rho C \) and a kind of “piezoelectric impedance”: \( \rho B \). This expression nicely reduces to an expression that depends only on the elastic impedance when \( B = 0 \).

### 5.2.1 Reduction to two layers

When a scattering element with two layers is used to construct a periodic bulk material, it will always have inversion symmetry. Therefore, to generate \( \tilde{S} \) and \( \tilde{W} \) Pernas-Salamón and Shmuel [41] broke spatial symmetry in their one-dimensional example using a periodic cell that is made of three layers. To enable a comparison with previous work, we have considered here a three-layer stack in the present work. (Note that our calculations show that in the low frequency regime, the effective properties \( \tilde{C}, \tilde{\rho}, \tilde{B} \) and \( \tilde{A} \) for three-layer elements and their periodic counterpart are the same.) However, it is clear that a two-layer scatterer in a background medium is sufficient to break inversion symmetry, and that expressions for bilayer elements are obtained as a particular case of the above results by setting \( l_3 = 0 \). In that case, the expressions for \( \tilde{C}, \tilde{\rho}, \tilde{A}, \) and \( \tilde{B} \) remain the same, only now the averaging is over two layers. The
expressions for $\tilde{S}$ and $\tilde{W}$, on the other hand, simplify to the following expressions

$$
\tilde{S} = \frac{i\omega}{2l} \tilde{C} l_1 l_2 \left[ A_1 A_2 \langle A^{-1} \rangle \Delta_{21} (Z_E^2) + B_1 B_2 \langle B^{-1} \rangle \Delta_{21} (B \rho) \right] + \mathcal{O} \left( \omega^2 \right),
$$

$$
\tilde{W} = \frac{i\omega}{2l} \tilde{B} l_1 l_2 \langle \rho \rangle \Delta_{21} \left( \frac{B}{A} \right) + \mathcal{O} \left( \omega^2 \right).
$$

Eq. (43) reproduces the same functional dependency of $\tilde{S}$ and $\tilde{W}$ as the three-layer expressions, in a simpler form. Eq. (43a) shows that the Willis coupling depends on the asymmetry in the elastic impedance, $\rho C$, as it is well known from the elastic case, and on the asymmetry in the piezoelectric-like impedance, $\rho B$. Eq. (43b) shows that the electromomentum coupling depends on the asymmetry in the ratio between the piezoelectric coefficient and the permittivity, $B/A$. Notably, the sign of $\tilde{S}$ and $\tilde{W}$ changes when the ordering of the layers is reversed with respect to the coordinate system, since $\Delta_{12} (\cdot) = -\Delta_{12} (\cdot)$.

The fact that $\tilde{S}$ and $\tilde{W}$ depend on asymmetries of different physical quantities has a very important implication: certain compositions of the piezoelectric element may exhibit zero Willis coupling and finite electromomentum coupling. This implies that we turn on and off the directional phase asymmetry by the opening and closing the circuit, respectively. One such design rule is $\rho_1 C_1 = \rho_2 C_2$, $\rho_1 B_1 = \rho_2 B_2$ and $B_1 A_1^{-1} \neq B_2 A_2^{-1}$. We note that we have implemented this design rule (i.e., $\rho C$ and $\rho B$ are spatially constant) for a trilayer periodic medium in the rigorous periodic homogenization scheme of Ref. [41]. Interestingly, we found that it also works in the low frequency regime of the periodic case, namely, we received a zero Willis coupling and a nonzero the electromomentum coupling.

### 5.2.2 Generalization to an arbitrary number of layers and the continuous limit

The low frequency expressions of Eq. (41) for $\tilde{\rho}$, $\tilde{C}$, $\tilde{A}$, $\tilde{B}$, $\tilde{S}$ and $\tilde{W}$ can be generalized to the case of an arbitrary number of $n > 3$ layers. The only change needed is to replace the upper limits, 2 and 3, of the sums over $p$ and $q$ in Eq. (41) by $n - 1$ and $n$, respectively. The continuous limit, i.e., when the properties of the element vary smoothly ($f_p \to f(x)$), corresponds to $n \to \infty$, in which case the sums are replaced by integrals and the average of a continuous property is simply $\langle f \rangle = \int_0^l f \, dx$. In summary, in the continuous limit $\tilde{\rho}$, $\tilde{C}$ and $\tilde{A}$ are exactly as shown in Eq. (41), while the expressions for $\tilde{B}$, $\tilde{S}$ and $\tilde{W}$ are
replaced by

\[
\tilde{B} = \left\langle \frac{B}{AC_D} \right\rangle \left[ \langle A^{-1} \rangle \langle C_D^{-1} \rangle - l^{-2} \int_0^l \frac{dx}{C_D(x)} \int_x^l \frac{dy}{C_D(y)} \left( \frac{B(x)}{A(x)} - \frac{B(y)}{A(y)} \right)^2 \right]^{-1} + \mathcal{O} (\omega^2), \tag{44a}
\]

\[
\tilde{S} = -i \omega l \tilde{C} \left\langle \left\langle \rho_D, \frac{1}{2C_D} \left( 1 + \gamma \frac{B}{A} \right) \right\rangle \right\rangle + \mathcal{O} (\omega^2), \tag{44b}
\]

\[
\tilde{W} = i \omega \frac{B}{AC_D} \int_0^l \frac{dx}{C_D(x)} \int_x^l \frac{dy}{C_D(y)} \left( \frac{B(x)}{A(x)} - \frac{B(y)}{A(y)} \right) \int_x^y \rho(z) dz + \mathcal{O} (\omega^2), \tag{44c}
\]

where the double average \( \left\langle \left\langle f, g \right\rangle \right\rangle \) of two material functions \( f \) and \( g \) is defined as

\[
\left\langle \left\langle f, g \right\rangle \right\rangle = l^{-2} \int_0^l f(x) dx \int_0^x g(y) dy - l^{-2} \int_0^l g(x) dx \int_0^x f(y) dy. \tag{45}
\]

Note that the double average is asymmetric in the two material parameters: \( \langle\langle f, g \rangle\rangle = -\langle\langle g, f \rangle\rangle \). Also, the identity \( Z_D^2 = \rho_D C_D \) has been used to simplify \( \tilde{S} \) in Eq. (44b).

From the above expressions for an arbitrary number of layers, we further deduce that elements that are made of a repetition of a certain unit cell have the same low-frequency effective properties, independent of the number of cells used to construct them. This is due to the fact that these expressions have the form of volume averages that remain invariant when you add to the element the same cell. This conclusion is evident from the expressions for \( \tilde{\rho}, \tilde{C} \) and \( \tilde{A} \), and less evident—but still holds—for the other moduli, as we also observed in a numerical study provided in Appendix D).

### 5.2.3 The source of the directional imaginary part of \( \tilde{B}^{eq} \)

Using low frequency expansions, we can also explicitly identify the source of the directional imaginary part of \( \tilde{B}^{eq} \). To this end, we expand Eq. (31) in power series about \( \omega = 0 \), and obtain the low frequency approximation

\[
\tilde{B}^{eq}_L = \tilde{B} - \tilde{W} \tilde{B} \gamma^{-1} Z_0^{-1}, \quad \tilde{B}^{eq}_R = \tilde{B} + \tilde{W} \tilde{B} \gamma^{-1} Z_0^{-1}, \tag{46}
\]

where \( \tilde{B} \) and \( \tilde{W} \) are given in Eqs. (41d) and (41f), respectively. Thus, \( \tilde{B}^{eq} \) is a sum of a real quantity (\( \tilde{B} \)) and an imaginary quantity (\( \tilde{W} \)), where the latter multiplies a sign that depends on the incident wave direction. Thus, for the equivalent model to recover the scattering response of the element, it must absorb the directional phase change that \( \tilde{W} \) models into \( \tilde{B}^{eq} \), thereby leading to a piezoelectric coefficient that violates reciprocity and energy conservation. (For similar absorbance of a Willis coupling into an equivalent property see Eq. (20) in Ref. [39]. Indeed, the resultant equivalent properties there—although not referred to as such there—violate causality.)
Table 1: Physical properties of the materials that are used in the computations as the constituents of the element.

<table>
<thead>
<tr>
<th>Material</th>
<th>$C$ (GPa)</th>
<th>$\rho$ (kg/m$^3$)</th>
<th>$B$ (C/m$^2$)</th>
<th>$A$ (nF/m)</th>
</tr>
</thead>
<tbody>
<tr>
<td>PZT4</td>
<td>115</td>
<td>7500</td>
<td>15.1</td>
<td>5.6</td>
</tr>
<tr>
<td>BaTiO$_3$</td>
<td>165</td>
<td>6020</td>
<td>3.64</td>
<td>0.97</td>
</tr>
<tr>
<td>PVDF</td>
<td>12</td>
<td>1780</td>
<td>-0.027</td>
<td>0.067</td>
</tr>
<tr>
<td>PMMA</td>
<td>3.3</td>
<td>1188</td>
<td>0</td>
<td>0.023</td>
</tr>
<tr>
<td>Fictitious phase</td>
<td>143.27</td>
<td>6020</td>
<td>18.81</td>
<td>0.97</td>
</tr>
</tbody>
</table>

6 Numerical experiments

In this Section, we apply the procedure in Sec. 4 to numerically calculate the effective properties of two different piezoelectric elements connecting two elastic waveguides made of PMMA. The physical properties of the PMMA, as well as the piezoelectric layers to be considered are given in Table 1. All the calculations to follow are presented as functions of frequency $f = \omega/2\pi$ over the range $0 - 20$ kHz, in which we have found that the low frequency expansions and the original expressions practically coincide. (The difference is less than 0.1%).

In the first example, we demonstrate the calculation of $\tilde{W}$, and show that when the element (or, equivalently, the coordinate system) is inverted, the electromomentum modulus changes sign, as it should, since it models an anisotropic material response and hence its value depends on the coordinate system. We show that together with this modulus, the effective properties are physically admissible; by contrast, we show that the equivalent properties of the element, albeit recover the same scattering, are physically invalid since they violate energy conservation and reciprocity. The second example not only provides another demonstration of the above observations, but also exhibits a distinctive inconsistency in the retrieved Willis modulus when using the equivalent model.

The first element that we analyze is made of 2.62 mm PZT4 (layer 1), 0.19 mm BaTiO$_3$ (layer 2) and 0.19 mm PVDF (layer 3). As mentioned, we also analyze the properties that are retrieved when the element is inverted (or rotated 180°), i.e., when layers 1 and 3 are interchanged. Figure 2a shows the pure imaginary Willis coupling. Values retrieved from the element ($\tilde{S}^c$, black squares) and its inversion ($\tilde{S}^a$, blue squares) satisfy $\tilde{S}^b = -\tilde{S}^c$. Figure 2b shows the pure imaginary electromomentum coupling. Like $\tilde{S}$, $\tilde{W}$ depends on the orientation (or polarization) of the element: values retrieved from the element ($\tilde{W}^c$, black circles) and its inversion ($\tilde{W}^a$, blue circles) satisfy $\tilde{W}^b = -\tilde{W}^c$. Again, we note that this result is consistent with the fact that these moduli model a direction-dependent material response, hence depend on the orientation of the element, or, equivalently, the orientation of the coordinate system.

Figure 2c presents the values of the standard effective properties, where each property is normalized by its arithmetic mean (normalized properties are denoted by overhead hat). Specifically, the brown, red, green and black curves correspond to $\hat{\rho}$, $\hat{C}$, $\hat{A}$ and $\hat{B}$, respectively. The computation delivers real constants that are independent of the direction of the incident wave, orientation of the element and the
FIG. 2: Retrieved properties of the PZT4-BaTiO-PVDF element and its inversion (see insets) as functions of frequency. (a) The pure imaginary Willis coupling. Values retrieved from the element ($\tilde{S}^\omega$, black squares) and its inversion ($\tilde{S}^\vartriangleright$, blue squares) satisfy $\tilde{S}^\omega = -\tilde{S}^\vartriangleright$. (b) The pure imaginary electromomentum coupling. Values retrieved from the element ($\tilde{W}^\omega$, black circles) and its inversion ($\tilde{W}^\vartriangleright$, blue circles) satisfy $\tilde{W}^\omega = -\tilde{W}^\vartriangleright$. (c) The standard effective properties, each one is normalized by its arithmetic mean. Brown, red, green and black curves correspond to $\hat{\rho}$, $\hat{C}$, $\hat{A}$ and $\hat{B}$, respectively. (d) The equivalent piezoelectric coefficient $\tilde{B}^\text{eq}$ that is retrieved from the short circuit experiment. Values extracted from the fields that are generated by leftward- and rightward incident waves are denoted by $\tilde{B}^\text{eq}_{sL}$ and $\tilde{B}^\text{eq}_{sR}$, respectively. While Re $\tilde{B}^\text{eq}_{sL}$ (blue curve) is equal to Re $\tilde{B}^\text{eq}_{sR}$ (gray curve), we observe that Im $\tilde{B}^\text{eq}_{sL}$ (green diamond marks) is nonzero and different from Im $\tilde{B}^\text{eq}_{sR}$ (red diamond marks), thereby violating energy conservation and reciprocity.
circuit conditions. As such, the effective properties are physically admissible.

We compute next the equivalent properties, based on the model that ignores the electromomentum coupling, in order to demonstrate that this model delivers unphysical moduli. To show this, it is sufficient to examine the retrieved piezoelectric coefficient \( \tilde{B}^{eq} \) as per the short circuit experiment [Eq. (31)], denoted \( \tilde{B}^{eq}_s \). In this case, the equivalent piezoelectric modulus also depends on the direction of the incoming waves, hence we denote values extracted from the fields that are generated by leftward- and rightward incoming waves by \( \tilde{B}^{eq}_{sL} \) and \( \tilde{B}^{eq}_{sR} \), respectively. Results are shown in Fig. 2d, which depicts the real and imaginary parts of \( \tilde{B}^{eq}_{sL} \) and \( \tilde{B}^{eq}_{sR} \) by the grey (blue) curve and green (red) diamonds, respectively. Indeed, in contrast with the purely real, direction-independent value of \( \tilde{B}^{eq}_s \), we observe that \( \tilde{B}^{eq}_s \) is a complex-valued, direction-dependent function, as \( \tilde{B}^{eq}_{sL} \) has an imaginary part that is different from the imaginary part of \( \tilde{B}^{eq}_{sR} \). The existence of an imaginary part in the equivalent piezoelectric modulus violates energy conservation, while the dependency of the modulus on direction of the incoming wave violates reciprocity. This violation occurs because \( \tilde{B}^{eq}_s \) erroneously subsumes the directional phase change that the electromomentum modulus models. Hence, the equivalent properties lose their physical meaning, even though they recover the scattering response of the element in the short circuit experiment.

As mentioned previously, there is another inconsistency in the equivalent model: the Willis modulus that the equivalent model retrieves from the short circuit experiment is different from the value that the equivalent model retrieves for the open circuit experiment. For this piezoelectric element, the difference between the two results is minor and not presented here. Essentially, this difference is proportional to the difference in the directional phase change in the two experiments. To demonstrate that this difference can be prominent, in the second example we make use of the conclusion in Sec. 5, namely, that \( \tilde{S} \) is zero when \( \rho C \) and \( \rho B \) are constant in the element, and that \( \tilde{W} \) is nonzero when \( B/A \) is asymmetric in the element. Accordingly, the second element that we consider is a bilayer made of 1.5 mm PZT4 and a 1.5 mm of an artificial material, the properties of which are set according to the above rule (see Tab. 1 for the corresponding values). While the properties of the second constituent are fictitious, they are close to the properties of real materials, and guide the selection of available constituents when the objective is to design a real element that will approximate this artificial one.

We present first in Fig. 3a the difference in the phase of the right (\( r_R \)) and left (\( r_L \)) reflection coefficients in the open circuit (solid blue line) and short circuit (dashed black line) experiments on the bilayer. Indeed, following our design rule, the phase of the two reflection coefficients is the same only when the circuit is shorted. We present next in Fig. 3b the retrieved effective \( \tilde{S} \) and \( \tilde{W} \) of the element, as well as of the inverted element (same legend as in Fig. 2) The computation shows that \( \tilde{S} \) is null, since the right and left reflection coefficients in the short circuit experiment are equal. By contrast, the modulus \( \tilde{W} \) is a nonzero, purely imaginary function, since \( r_R \) and \( r_L \) in the open circuit experiment differ by a phase, while \( \tilde{S} = 0 \). Before we proceed to analyze the equivalent properties of the element, we note that the electromomentum modulus of the element is opposite in sign to the the electromomentum modulus of
FIG. 3: (a) The difference between the phase of the right ($r_R$) and left ($r_L$) reflection coefficients in the open circuit (solid blue line) and short circuit (dashed black line) experiments on the bilayer. According to our design rule, the former is nonzero and the latter is zero. (b) The effective Willis modulus $\tilde{S}$ and electromomentum modulus $\tilde{W}$ of the element. Same legend as in Fig. 2. The modulus $\tilde{S}$ is null, since the right- and left reflection coefficients in the short circuit experiment are equal. The modulus $\tilde{W}$ is a nonzero, pure imaginary function, since the right- and left reflection coefficients in the open circuit experiment differ by a phase, while $\tilde{S} = 0$.

FIG. 4: Retrieved equivalent properties of the bilayer. (a) The pure imaginary $\tilde{S}^{eq}$ as retrieved for the element (green markers) and its inversion (red markers) when the circuit is open ($\tilde{S}^{eq}_o$, circle marks) and shorted ($\tilde{S}^{eq}_s$, triangle marks). The fact that $\tilde{S}^{eq}_s \neq \tilde{S}^{eq}_o$ implies that the equivalent model is inconsistent. (b) The equivalent piezoelectric coefficient $\tilde{B}^{eq}$ that is retrieved from the short circuit experiment. Same legend as in Fig. 2. Again, the direction-dependent imaginary part of $\tilde{B}^{eq}$ is a violation of reciprocity and energy conservation.
the inverted element, as in the first example.

The Willis modulus that is retrieved from the short circuit experiment using the equivalent model \( \tilde{S}_{eq} \) is denoted in Fig. 4a by triangle marks, where the green and red colors denote the element and its inversion, respectively. As per our analysis in Sec. 4, the electromomentum effect is not apparent under short circuit conditions, and hence the equivalent Willis modulus that is retrieved in this setting coincides with the effective modulus. Specifically, for this element—which does not generate a phase difference in the short circuit experiment—both models retrieve a null Willis coefficient. However, since there is a phase difference between the reflection coefficients in the open circuit experiment, the equivalent model will need a nonzero \( \tilde{S}_{eq} \) to capture this. The retrieved values of the equivalent model in the open circuit experiment \( \tilde{S}_{eq}^o \) are denoted in Fig. 4a by circle marks. As expected, we observe that \( \tilde{S}_{eq}^o \) is different from \( \tilde{S}_{eq}^s \): the latter is identically zero and the former is not. This discrepancy provides further evidence for the need to include the electromomentum modulus in the effective constitutive relations.

We conclude the analysis of this element by showing that the equivalent model also fails in retrieving a physical piezoelectric modulus, as in the example of the first element. This is demonstrated in Fig. 4b, which shows the calculation of \( \tilde{B}_{eq}^s \) that is extracted from the short circuit experiment [Eq. (31)] (same legend as in Fig. 2). Again, the equivalent piezoelectric modulus has an imaginary part, hence does not respect energy conservation. Moreover, this imaginary part depends on the direction of the incident waves, hence it does not respect reciprocity either.

Finally, before summarizing the results of this work, we refer the reader to Appendix D, where we numerically evaluate the exact expressions (i.e., before applying the Taylor approximation) of different elements made of a repetition of the trilayer considered in Fig. 2.

7 Summary

By adapting the homogenization theory of Willis \([56, 57, 60, 61, 62]\) to piezoelectric composites, Pernas-Salomón and Shmuel \([41]\) have found that a macroscopic cross-coupling between the momentum and electric field emerges if the media has broken inversion symmetry. The electromomentum coupling constitutes an additional degree of freedom in the design space of metamaterials, which reflects an unusual interplay between the kinetic energy and electric energy at the macroscale. The objective of this work was to provide a heuristic demonstration of this coupling, analyze its effect, and elucidate its physical origins.

Towards this end, we have analyzed first the effect of the electromomentum coupling on plane waves in homogenized media under short circuit and open circuit conditions. This analysis shows that only under open circuit conditions, the coupling modifies the phase velocity and introduces a directional phase angle to the characteristic elastic impedance. The former feature is similar to the effect that the piezoelectric coupling has on the phase velocity, and the latter feature is similar to the effect that the Willis
coupling has on the characteristic impedance.

The analysis suggests that these features can be quantified from the scattering properties of a one-dimensional asymmetric piezoelectric scatterer. To do so, we have calculated analytically its scattering coefficients in response to rightward- and leftward incident waves, under the two circuit conditions. We then used an inverse program to determine the properties of a homogenized medium according to two models: an effective model that includes both Willis and electromomentum coupling, and an equivalent model that neglects electromomentum coupling [14, 31, 48]. This heuristic homogenization approach is applicable only in the long-wavelength, low frequency regime [49]. The conclusions that we have found and demonstrated numerically correspond to this limit, are summarized next.

We highlight the main observation from this analysis: the reflection of rightward- and leftward incident waves is different by a phase, where this phase depends on the electric circuit conditions, i.e., if the circuit is shorted or open. It is precisely the extra phase in the open circuit that only the electromomentum coupling captures. Together with this coupling, the properties that are retrieved from the scattering experiments using the effective model satisfy reciprocity and energy conservation, and are independent of the excitation setup. By contrast, the properties of the equivalent model that are retrieved from the short circuit setup violate reciprocity and energy conservation, and are different from the values that are retrieved from the open circuit setup, even in the low frequency regime. We note that such violations of physical laws by equivalent models that neglect the electromomentum coupling were also found in studies of infinite piezoelectric media using rigorous homogenization, based on ensemble averaging, see Ref. [29].

We have obtained explicit expressions for the low frequency approximations of the effective properties of element with an arbitrary number of layers using Taylor expansions. These expressions show that elements that are made of a repetition of a certain unit cell have the same effective properties at low frequencies, independently of the number of cells used to construct those elements. The leading term in the expansions of the effective mass, stiffness and permittivity is a real constant that agrees with their expected value from static homogenization in the limiting decoupled case. By contrast, the leading term in the expansions of the Willis coupling and the electromomentum coupling is a linear function of the frequency, and purely imaginary, hence responsible for the phase change. The expansion of the former clearly shows that the Willis coupling depends on the asymmetry in the impedance—as known in the elastic case—and the asymmetry in a kind of a piezoelectric impedance, that is the product of the piezoelectric coefficient by the mass density. The leading term in the expansion of the electromomentum coupling depends on the asymmetry in ratio between the piezoelectric constant and the permittivity. Hence, it is possible to design elements that have zero Willis coupling and finite electromomentum coupling. The directional phase angle of such element vanishes in the short circuit setup—since it depends only on the Willis coupling—and persists in the open circuit setup since it depends on the electromomentum coupling. This observation suggests a convenient way to control the directional phase change by the
opening and shorting of the circuit.

We expect the demonstration of the electromomentum effect in this simple setting to promote further studies of its implications in more general settings, and its engineering for applications that require control over elastic waves.

Acknowledgments

We thank anonymous reviewers for useful comments that helped us improve this paper. This research was supported by the Israel Science Foundation, funded by the Israel Academy of Sciences and Humanities (Grant no. 2061/20), the United States-Israel Binational Science Foundation (Grant no. 2014358), and Ministry of Science and Technology (Grant no. 880011). A.N.N. and M.R.H. acknowledge support from NSF EFRI award no. 1641078 and M.R.H. acknowledges additional support ONR YIP award no. N00014-18-1-2335.

Appendix A.

The transfer matrix for the mechanical fields of the homogenized medium in short circuit.

Consider a finite slab of homogeneous medium governed by Eq. (3), admitting plane waves of the form \( u(x, t) = U e^{\pm i k_E x - i \omega t} \). In a short circuit configuration such that the electric field vanishes, its stress and momentum reduce to the Willis form

\[
\sigma = \tilde{C} u,_{,x} - i \omega \tilde{S} u, \quad (A.1)
\]
\[
p = \tilde{S}^\dagger u,_{,x} - i \omega \tilde{\rho} u. \quad (A.2)
\]

We extract the strain from Eq. (A.1):

\[
u,_{,x} = \tilde{C}^{-1} \sigma + i \omega \tilde{S} \tilde{C}^{-1} u, \quad (A.3)
\]

substitute it into Eq. (A.2), and then use the resultant expression for \( p \) in the governing equation \( \sigma,_{,x} = -i \omega p \) to obtain

\[
\sigma,_{,x} = -i \omega \tilde{S}^\dagger \tilde{C}^{-1} \sigma + \omega^2 \left( \tilde{S} \tilde{S}^\dagger \tilde{C}^{-1} - \tilde{\rho} \right) u. \quad (A.4)
\]
Equations A.3) and (A.4) are written in matrix form as

\[
\begin{pmatrix}
  u_{,x} \\
  \sigma_{,x}
\end{pmatrix} = M
\begin{pmatrix}
  u \\
  \sigma
\end{pmatrix}
\]
where

\[
M = \begin{pmatrix}
  i\omega \tilde{S} \tilde{C}^{-1} & \tilde{C}^{-1} \\
  \omega^2 \left( \tilde{S} \tilde{S}^\dagger \tilde{C}^{-1} - \tilde{\rho} \right) & -i\omega \tilde{S} \tilde{C}^{-1}
\end{pmatrix}.
\]

(A.5)

Considering plane wave solutions, Eq. (A.5) leads to the following relation between the displacement and stress at two different points in the slab:

\[
\begin{pmatrix}
  u(x_b) \\
  \sigma(x_b)
\end{pmatrix} = T^m(x_b, x_a)
\begin{pmatrix}
  u(x_a) \\
  \sigma(x_a)
\end{pmatrix}, \quad x_0 \leq x_a, x_b \leq x_3,
\]

(A.6)

where

\[
T^m(x_b, x_a) = e^{(x_b - x_a)M}
\]

(A.7)

is the transfer matrix relating the displacement and stress fields at the space coordinates \(x_a\) and \(x_b\).

**Appendix B.**

**Retrieved properties in the clamped ends configuration.**

This appendix provides an analysis of a third setup that verifies the consistency of the effective properties. We consider a setup with zero average strain by clamping the ends \(x_0\) and \(x_3\), and excite the stack by applying a time harmonic \((e^{-i\omega t})\) voltage drop. (This configuration is consistent with an effective stress-charge form since we evaluate the effective permittivity and piezoelectric coefficients at a prescribed effective strain when an electric field generates stress and electric displacement field.)

We determine the effective properties from the requirement that the fictitious medium will deliver the same average fields as in the piezoelectric stack. To this end, we first calculate the exact fields in the stack, as follows. From Eq. (15) we obtain

\[
\sigma(x_0) = -\frac{T^p_{14}}{T^p_{13}} D,
\]

(B.1)

which together with Eqs. (14) and (B.1) determine \(u(x)\) and \(\sigma(x)\) as

\[
u(x) = \begin{cases}
  D \left( \frac{B_1}{A_1} - \frac{T^p_{14}}{T^p_{13}} \right) \frac{\sin k_{D1} (x - x_0)}{\omega Z_{D1}}, & x_0 \leq x \leq x_1, \\
  u(x_1) \cos k_{D2} (x - x_1) + \left[ \sigma(x_1) + \frac{B_2}{A_2} D \right] \frac{\sin k_{D2} (x - x_1)}{\omega Z_{D2}}, & x_1 \leq x \leq x_2, \\
  u(x_2) \cos k_{D3} (x - x_2) + \left[ \sigma(x_2) + \frac{B_3}{A_3} D \right] \frac{\sin k_{D3} (x - x_2)}{\omega Z_{D3}}, & x_2 \leq x \leq x_3,
\end{cases}
\]

(B.2)
where $T_t = T_3^e T_2^e T_1^e$ and

$$
u(x_1) = \left( T_{11}^e - T_{13}^e \frac{T_{14}^e}{T_{13}^e} \right) D, \quad \nu(x_2) = T_{21}^e \nu(x_1) + T_{23}^e \nu(x_1) + T_{24}^e D, \quad (B.3)$$

and $T_{n}^{e}_{n(ij)}$ is the $ij$-component of the matrix $T_{n}^e$. The stress as function of $x$ is $\sigma(x) = C_D u_{x} - (B_n/A_n) D$, for $x_{n-1} \leq x \leq x_n, n = 1, 2, 3$. Furthermore, from Eqs. (15) and (B.1) we have that

$$\phi(x_3) - \phi(x_0) = \left( T_{24}^e - T_{23}^e \frac{T_{14}^e}{T_{13}^e} \right) D. \quad (B.5)$$

Having determined $\nu(x)$ and $\sigma(x)$ allows us to average over the stack, which together with Eq. (B.5) and the fact that (in absence the of charge) $D$ is constant in the stack provide

$$l \langle \nu \rangle = \Gamma_1^e \langle D \rangle, \quad l \langle \sigma \rangle = \Gamma_2^e \langle D \rangle, \quad l \langle \phi, x \rangle = \Gamma_3^e \langle D \rangle, \quad (B.6)$$

where the terms $\Gamma_i^e$ are

$$\Gamma_1^e = \left( \frac{B_1}{A_1} - \frac{T_{14}^e}{T_{13}^e} \right) \frac{1 - \cos k D_1 l_1}{\omega k D_1 Z_D}$$

$$+ \left( T_{11}^e - T_{13}^e \frac{T_{14}^e}{T_{13}^e} \right) \frac{\sin k D_2 l_2}{k D_2} + \left( T_{11}^e - T_{13}^e \frac{T_{14}^e}{T_{13}^e} + \frac{B_2}{A_2} \right) \frac{1 - \cos k D_2 l_2}{\omega k D_2 Z_D}$$

$$+ \left[ T_{21}^e \left( T_{11}^e - T_{13}^e \frac{T_{14}^e}{T_{13}^e} \right) + T_{23}^e \left( T_{11}^e - T_{13}^e \frac{T_{14}^e}{T_{13}^e} + \frac{B_2}{A_2} \right) \right] \frac{\sin k D_3 l_3}{k D_3}$$

$$+ \left[ T_{21}^e \left( T_{11}^e - T_{13}^e \frac{T_{14}^e}{T_{13}^e} \right) + T_{23}^e \left( T_{11}^e - T_{13}^e \frac{T_{14}^e}{T_{13}^e} + \frac{B_2}{A_2} \right) \right] \frac{1 - \cos k D_3 l_3}{\omega k D_3 Z_D} \quad (B.7)$$
permittivity if neglect it as in the equivalent model; by contrast, the equivalent permittivity is different from the effective fields. Since we use the equations for the average stress and electric displacement field when the average strain is zero, then the retrieved piezoelectric coefficient is the same whether we use \( \bar{W} \) as in model (3), or neglect it as in the equivalent model; by contrast, the equivalent permittivity is different from the effective permittivity if \( \bar{W} \) is neglected. When \( \bar{W} \) is included, the effective properties read

\[
\Gamma_2^o = \left( \frac{B_1}{A_1} - \frac{T_{14}^o}{T_{13}^o} \right) \frac{\sin k_{D1} l_1}{k_{D1}} - \frac{B_1}{A_1} l_1 \\
+ \left( \frac{T_{14}^o}{T_{13}^o} - \frac{B_2}{A_2} \right) \frac{\sin k_{D2} l_2}{k_{D2}} - \omega Z_{D2} \left( \frac{T_{14}^o}{T_{13}^o} - \frac{T_{1(33)}^o}{T_{13}^o} \right) \frac{1 - \cos k_{D2} l_2}{k_{D2}} - \frac{B_2}{A_2} l_2 \\
+ \left[ \frac{T_{2(31)}^o}{T_{13}^o} \right] \left( \frac{T_{14}^o}{T_{13}^o} - \frac{T_{1(13)}^o}{T_{13}^o} \right) + \frac{T_{2(33)}^o}{T_{13}^o} \left( \frac{T_{14}^o}{T_{13}^o} - \frac{T_{1(33)}^o}{T_{13}^o} \right) + \frac{T_{2(34)}^o}{T_{13}^o} + \frac{B_3}{A_3} \frac{\sin k_{D3} l_3}{k_{D3}} - \frac{B_3}{A_3} l_3, \\
\] (B.8)

\[
\Gamma_3^o = T_{24}^o - T_{23}^o \frac{T_{14}^o}{T_{13}^o}. \\
\] (B.9)

We are now in a position to determine the effective properties from the relations between average fields. Since we use the equations for the average stress and electric displacement field when the average strain is zero, then the retrieved piezoelectric coefficient is the same whether we use \( \bar{W} \) as in model (3), or neglect it as in the equivalent model; by contrast, the equivalent permittivity is different from the effective permittivity if \( \bar{W} \) is neglected. When \( \bar{W} \) is included, the effective properties read

\[
\bar{A}^o = \frac{l + i \omega \bar{W}^o}{\Gamma_3^o} \Gamma_1^o, \quad \bar{B}^o = \frac{\Gamma_2^o + i \omega \bar{S}_o^e \Gamma_1^o}{\Gamma_3^o}; \\
\] (B.10)

here, we use superscript ^o to distinguish the results for this element from the results for an inverted element, the layers 1 and 3 of which are interchanged. Eq. (B.10) provides a third equation to determine \( \bar{W} \). Thus, together with Eq. (35a) we obtain

\[
\bar{W}^o = - \frac{l \left( \bar{S}_o^e - \bar{S}^o \right)}{\Gamma_2^o + i \omega \bar{S}_o^e \Gamma_1^o}; \\
\] (B.11)

where \( \bar{S}_o^e \) equals the right-hand side of Eq. (35a). We note that if \( \bar{W} \) is neglected, then the expressions for the equivalent permittivity from this experiment is determined by setting \( \bar{W} = 0 \) in Eq. (B.10).

It is straightforward to carry out the same analysis if the element is inverted, i.e., if layers 1 and 3 in the element are interchanged. In this case \( \bar{A}^o \) and \( \bar{B}^o \) of the inverted element are given by

\[
\bar{A}^o = - \frac{l + i \omega \bar{W}^o \Gamma_1^o}{\Gamma_3^o}, \quad \bar{B}^o = \frac{\Gamma_2^o + i \omega \bar{S}_o^e \Gamma_1^o}{\Gamma_3^o}; \\
\] (B.12)

here, \( \Gamma_1^o, \Gamma_2^o \) and \( \Gamma_3^o \) correspond to the case where layers 1 and 3 of the laminate are swapped, and can be obtained, respectively, from the expressions for \( \Gamma_1^o, \Gamma_2^o \) and \( \Gamma_3^o \) by interchanging the properties and matrices corresponding to the layers 1 and 3, and replacing the matrix \( T^o \) by the matrix \( T^a = T_{14}^{em} T_{24}^{em} T_{34}^{em} \).
Again, by substituting Eq. (B.12) into Eq. (35a) we obtain

\[
\tilde{W}^a = -\frac{l \left( \tilde{S}_0^{\text{eq}} - \tilde{S}^a \right)}{\Gamma_1^a + i\omega \tilde{S}_0^{\text{eq}} \Gamma_1^a},
\]

where \( \tilde{S}_0^{\text{eq}} \) is given by the right-hand side of Eq. (35a) for the inverted element. Now, since Eqs. (14) and (15) verify that \( \Gamma_1^a = -\Gamma_1^a, \Gamma_2^a = \Gamma_2^a \) and \( \Gamma_3^a = \Gamma_3^a \), and Eqs. (28a) and (35a) imply that \( \tilde{S}^a = -\tilde{S}^\circ \) and \( \tilde{S}_0^{\text{eq}} = -\tilde{S}_0^{\text{eq}} \), and hence the electromomentum coupling changes sign when the element is inverted, i.e., \( \tilde{W}^a = -\tilde{W}^\circ \), like the Willis coupling. Together, the former imply that \( \bar{A}^a = \bar{A}^\circ, \bar{B}^a = \bar{B}^\circ \).

The above analysis demonstrates another inconsistency in the equivalent model that neglects \( \tilde{W} \): the extracted values for the equivalent piezoelectric coefficients are different in the short circuit experiment and in this experiment, i.e., Eq. (31) and Eq. (B.10)\(_2\), are different. This is evident from the fact that Eq. (31) is complex-valued, while Eqs. (B.10)\(_2\) is real-valued.

**Appendix C.**

**The coefficients in the alternative expression of \( \tilde{S} \).**

The constants that appear in Eq. (42) are

\[
\chi = \left( A_1 A_2 C_{D1} C_{D2} C_3 l_3 + A_1 A_3 C_{D1} C_{D3} C_2 l_2 + A_2 A_3 C_{D2} C_{D3} C_1 l_1 \right)^{-1} \tilde{C},
\]

and

\[
\begin{align*}
\alpha_1 &= A_2 A_3 C_1 l_1 + A_1 A_3 C_{D1} (A_2 l_3 + A_3 l_2), \quad \beta_1 = B_1 B_2 B_3 l_1 + A_1 C_{D1} (B_3 l_2 + B_2 l_3) \\
\alpha_2 &= A_1 A_3 C_2 l_2 + A_2 C_{D2} (A_1 l_3 + A_3 l_1), \quad \beta_2 = B_1 B_2 B_3 l_2 + A_2 C_{D2} (B_3 l_1 + B_1 l_3) \\
\alpha_3 &= A_1 A_2 C_3 l_3 + A_3 C_{D3} (A_1 l_2 + A_2 l_1), \quad \beta_3 = B_1 B_2 B_3 l_3 + A_3 C_{D3} (B_2 l_1 + B_1 l_2)
\end{align*}
\]

**Appendix D.**

**A comparison of the effective properties of elements with different number of cells beyond the quasistatic limit.**

In this Appendix, we numerically evaluate the exact expressions of the effective properties [i.e., those obtained from Eqs. (28), (35) and (38) not the asymptotic expressions] of elements made of a repetition...
of the trilayer considered in Fig. 2. The purpose is to provide an example, showing that (i) the first-order approximations hold beyond the quasistatic regime ($\tilde{k}a < 0.01$, $a$ being the lattice constant); (ii) the effective properties of different elements made of the same cell are equal, independent of the number of cells used to construct the element. These features are shown in Fig. 5. Specifically, panels 5a-5f show the effective stiffness, mass density, dielectric-, piezoelectric-, Willis-, and electromomentum moduli of the elements, respectively, as functions of the frequency. Blue, black and brown correspond to one-, three- and six repetitions of the trilayer. We observe that up to a limiting frequency (which is not constant for all moduli), the effective properties of all three elements coincide.

The formal applicability limit of the quasistatic homogenization is usually quantified in terms of the effective wavenumber normalized by the lattice constant, say $a$, according to $\tilde{k}a < 0.01$ [50]. Since here we do not really have a lattice, only a number of unit cells, we choose to examine the effective wavenumber of the three elements, normalized by the length of each element, i.e., $\tilde{k}l$. This is shown in panel 5g. We observe that the limit $\tilde{k}l = 0.01$ corresponds to the frequencies 1890 Hz, 630 Hz and 315 Hz, for the elements with one-, three- and six cells, respectively. Notably, the first order approximations hold beyond those frequencies, as we see that the ordinary (resp. the Willis- and electromomentum) moduli in the previous panels are constant (resp. linear) beyond those frequency values. This observation agrees with the results in Ref. [9] for second order homogenization in one-dimensional elastodynamics.

We note that it is the size of the unit cell, $a$ that is important in determining the effective properties, not the size of the element. This is shown in Fig. 6, which is the same as Fig. 5, only now the length of all elements are equal, such that the size of each cell in an element is inversely proportional to the number of cells in that element. We observe that now the agreement between effective properties of the different elements is limited to a more narrow range of frequencies. Most notably, the Willis- and electromomentum moduli of the three elements are different at all frequencies, which is consistent with the low-frequency expansions for Willis coupling in acoustics, where the Willis coupling modulus has been shown to depend on the lattice constant [48].

References


FIG. 5: A comparison of the effective (a) stiffness; (b) mass density; (c) dielectric; (d) piezoelectric; (e) Willis; and (f) electromomentum moduli of elements made of repetitions of the element in the first example. Blue, black and brown correspond to one-, three- and six repetitions. (g) Normalized effective wavenumber of the three elements, $\tilde{k}l$, versus frequency, for the three elements.
FIG. 6: Same as Fig. 5, only now the size of the element is fixed, such that the size of each cell in an element is inversely proportional to the number of cells in that element.


